	^ ^	* Welcome to STN international * * * * * * * * *
NEWS 1		Web Page URLs for STN Seminar Schedule - N. America
NEWS 2		"Ask CAS" for self-help around the clock
NEWS 3 FEB	28.	PATDPAFULL - New display fields provide for legal status
		data from INPADOC
NEWS 4 FEB	28	BABS - Current-awareness alerts (SDIs) available
NEWS 5 MAR		GBFULL: New full-text patent database on STN
NEWS 6 MAR		REGISTRY/ZREGISTRY - Sequence annotations enhanced
NEWS 7 MAR		MEDLINE file segment of TOXCENTER reloaded
NEWS 8 MAR		KOREAPAT now updated monthly; patent information enhanced
NEWS 9 MAR		Original IDE display format returns to REGISTRY/ZREGISTRY
NEWS 10 MAR		PATDPASPC - New patent database available
NEWS 11 MAR		REGISTRY/ZREGISTRY enhanced with experimental property tags
NEWS 12 APR	04	EPFULL enhanced with additional patent information and new fields
NEWS 12 ADD	0.4	EMBASE - Database reloaded and enhanced
NEWS 13 APR NEWS 14 APR		
		New CAS Information Use Policies available online
NEWS 15 APR	25	Patent searching, including current-awareness alerts (SDIs),
		based on application date in CA/CAplus and USPATFULL/USPAT2
		may be affected by a change in filing date for U.S.
16 700	0.0	applications.
NEWS 16 APR	28	Improved searching of U.S. Patent Classifications for
	00	U.S. patent records in CA/CAplus
NEWS 17 MAY		GBFULL enhanced with patent drawing images
NEWS 18 MAY	23	REGISTRY has been enhanced with source information from
		CHEMCATS
NEWS 19 JUN	06	The Analysis Edition of STN Express with Discover!
		(Version 8.0 for Windows) now available
NEWS 20 JUN		RUSSIAPAT: New full-text patent database on STN
NEWS 21 JUN		FRFULL enhanced with patent drawing images
NEWS 22 JUN	27	MARPAT displays enhanced with expanded G-group definitions
		and text labels
NEWS 23 JUL		MEDICONF removed from STN
NEWS 24 JUL		STN Patent Forums to be held in July 2005
NEWS 25 JUL		SCISEARCH reloaded
NEWS 26 JUL	20	Powerful new interactive analysis and visualization software,
		STN AnaVist, now available
NEWS EXPRESS		NE 13 CURRENT WINDOWS VERSION IS V8.0, CURRENT
		CINTOSH VERSION IS V6.0c(ENG) AND V6.0Jc(JP),
	ANI	D CURRENT DISCOVER FILE IS DATED 13 JUNE 2005
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NEWS INTER		neral Internet Information
NEWS LOGIN		lcome Banner and News Items
NEWS PHONE		rect Dial and Telecommunication Network Access to STN
NEWS WWW	CA:	S World Wide Web Site (general information)

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FILE 'HOME' ENTERED AT 13:02:27 ON 28 JUL 2005

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=> file inspec
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COST IN U.S. DOLLARS SINCE FILE TOTAL

> ENTRY SESSION 0.21 0.21

FULL ESTIMATED COST

FILE 'INSPEC' ENTERED AT 13:02:53 ON 28 JUL 2005 Compiled and produced by the IEE in association with FIZ KARLSRUHE COPYRIGHT 2005 (c) INSTITUTION OF ELECTRICAL ENGINEERS (IEE)

FILE LAST UPDATED: 25 JUL 2005

<20050725/UP>

FILE COVERS 1969 TO DATE.

<>< SIMULTANEOUS LEFT AND RIGHT TRUNCATION AVAILABLE IN THE BASIC INDEX >>>

## => s silicon carbide substrate

336202 SILICON

25696 CARBIDE

176648 SUBSTRATE

46 SILICON CARBIDE SUBSTRATE T.1

(SILICON (W) CARBIDE (W) SUBSTRATE)

=> s cmos

58764 CMOS

=> s 1 and 2

1419292 1

1205084 2

671700 1 AND 2 L3

=> s 11 and 12

0 L1 AND L2 T.4

=> s silicon carbide

336202 SILICON

25696 CARBIDE

L5 11054 SILICON CARBIDE

(SILICON (W) CARBIDE)

=> s 12 and 15

27 L2 AND L5

=> d 16 1-27

ANSWER 1 OF 27 INSPEC (C) 2005 IEE on STN

DN A2005-16-0130C-023; B2005-08-0100-047; 2005:8487617 INSPEC AN C2005-08-0000-062

27th International Spring Seminar on Electronics Technology (IEEE Cat.

TΙ No.04EX830). SO

Piscataway, NJ, USA: IEEE, 2005. 3 vol. 580 pp. Conference: Bankya, Bulgaria, 13-16 May 2004

Price: CCCC 04/\$20.00 ISBN: 0-7803-8422-9

Conference Proceedings DT

CY United States

LA English L6 ANSWER 2 OF 27 INSPEC (C) 2005 IEE on STN



- AN 2004:8096409 INSPEC DN B2004-10-2550G-039
- TI A 90 nm dual damascene hybrid (organic/inorganic) low-k-copper BEOL integration scheme.
- AU Dalton, T.J. (IBM Res. Div., Semicond. Res. & Dev. Center, Yorktown Heights, NY, USA); Cowley, A.; Clevenger, L.; La Tulipe, D.; Li, W.-K.; Kumar, K.; Simon, A.; Kaldor, S.; Yang, C.-C.; Lin, Y.-H.; Hoinkis, M.; Schact, J.; Naujok, M.; Economikos, L.; Rovedo, N.; Olbrecht, A.; Wang, H.; Swift, A.; Li, B.; Chanda, K.; Lee, T.; Burrel, L.; Matusiewicz, G.; Fayaz, F.; Yang, S.; Yanagisawa, T.; Lu, N.; Angyal, M.; Dunn, D.; Ng, H.; Wann, C.; Crowder, S.; Chen, T.-C.
- Advanced Metallization Conference 2003 (AMC 2003)

  Editor(s): Ray, G.W.; Smy, T.; Ohla, T.; Tsujimura, M.

  Warrendale, PA, USA: Mater. Res. Soc, 2004. p.85-9 of xxiii+792 pp. 4 refs.

  Conference: Montreal, Que., Canada & Tokyo, Japan, 21-23 Oct 2003 & 29
- Sept-1 Oct 2003 DT Conference Article
- TC Practical; Experimental
- CY United States
- LA English
- L6 ANSWER 3 OF 27 INSPEC (C) 2005 IEE on STN



- AN 2004:7936705 INSPEC DN B2004-05-2575F-182
- TI Polyimide sacrificial layer for an all-dry post-process surface .micromachining module.
- AU Pham, H.T.M.; Bagolini, A.; de Boer, C.R.; Laros, J.M.W. (Inst. for Microelectron. & Submicron Technol., Delft Univ. of Technol., Netherlands); Pakula, L.; French, P.J.; Sarro, P.M.
- SO TRANSDUCERS '03. 12th International Conference on Solid-State Sensors, Actuators and Microsystems. Digest of Technical Papers (Cat. No.03TH8664) Piscataway, NJ, USA: IEEE, 2003. p.813-16 vol.1 of 2 vol.(xl+xxxix+1938) pp. 6 refs. Also available on CD-ROM in PDF format Conference: Boston, MA, USA, 8-12 June 2003 Sponsor(s): IEEE; Electron Devices Soc

ISBN: 0-7803-7731-1

- DT Conference Article
- TC Practical; Experimental
- CY United States
- LA English
- L6 ANSWER 4 OF 27 INSPEC (C) 2005 IEE on STN

Price: CCCC 0-7803-7731-1/03/\$17.00



- AN 2004:7884624 INSPEC DN B2004-04-2575F-008
- TI A CMOS compatible SiC accelerometer.
- AU Pakula, L.S.; Yang, H.; French, P.J. (DIMES, Delft Univ. of Technol., Netherlands)
- SO Proceedings of IEEE Sensors 2003 (IEEE Cat. No.03CH37498)
  Piscataway, NJ, USA: IEEE, 2003. p.761-4 Vol.2 of 1367 pp. 7 refs.
  Conference: Toronto, Ont., Canada, 22-24 Oct 2003

Sponsor(s): IEEE Sensors Council

Price: CCCC 0-7803-8133-5/03/\$17.00

ISBN: 0-7803-8133-5

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DT
     Conference Article
TC
     Application
CY
     United States
LА
     English
L6
     ANSWER 5 OF 27 INSPEC (C) 2005 IEE on STN
          2004:7862337
                              DN B2004-03-2550G-124
AN
                  INSPEC
.TI
     A novel graded antireflective coating with built-in hardmask properties
     enabling 65nm and below CMOS device patterning.
ΑU
     Babich, K. (IBM T. J. Watson Res. Center, Yorktown Heights, NY, USA);
     Fukiage, N.; Mahorowala, A.; Halle, S.; Bunner, T.; Pfeiffer, D.; Mochiki,
     H.; Ashigaki, S.; Xia, A.; Angelopoulos, M.
SO
     IEEE International Electron Devices Meeting 2003
     Pisacataway, NJ, USA: IEEE, 2003. p.28.5.1-4 of 999 pp. 5 refs.
     Conference: Washington, DC, USA, 8-10 Dec 2003
     Price: CCCC 0-7803-7872-5/03/$17.00
     ISBN: 0-7803-7872-5
DT
     Conference Article
TC
     New Development; Practical; Experimental
CY
     United States
     English
LA
1.6
     ANSWER 6 OF 27 INSPEC (C) 2005 IEE on STN
  FOII
TEST
ΑN
     2003:7509357 INSPEC
                              DN B2003-02-2550F-065
TI
     Advanced metal barrier free Cu damascene interconnects with PECVD
     silicon carbide barriers for 90/65-nm BEOL technology.
ΝA
     Wu, Z.C.; Lu, Y.C.; Chiang, C.C.; Chen, M.C.; Chen, B.T.; Wang, G.J.;
     Chen, Y.T.; Huang, J.L.; Jang, S.M.; Liang, M.S. (Dept. of Dielectric &
     CMP, Taiwan Semicond. Manuf. Co., Hsinchu, Taiwan)
     International Electron Devices Meeting. Technical Digest (Cat.
so
     No.02CH37358)
     Piscataway, NJ, USA: IEEE, 2002. p.595-8 of 957 pp. 5 refs.
     Conference: San Francisco, CA, USA, 8-11 Dec 2002
     Sponsor(s): Electron. Devices Soc. IEEE
     Price: CCCC 0-7803-7462-2/02/$17.00
     ISBN: 0-7803-7462-2
     Conference Article
DT
TC
     Application; Practical; Experimental
CY
     United States
     English
LA
L6
     ANSWER 7 OF 27
                     INSPEC (C) 2005 IEE on STN
            Text
     2000:6610704 INSPEC
                              DN B2000-07-2570D-006
AN
ΤI
     Study of the silicon carbide integrate circuits technique.
AU
     Wang Jian-Ping; Hao Yue; Peng Jun (Res. Inst. of Microelectron., Xidian
     Univ., Xi'an, China)
SO
     Journal of Xidian University (April 2000) vol.27, no.2, p.228-32. 8 refs.
     Published by: Xidian Univ
     CODEN: XDKXEP ISSN: 1001-2400
     SICI: 1001-2400(200004)27:2L.228:SSCI;1-7
     Journal
DT
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Experimental

China

Chinese

TC CY

LΑ

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ANSWER 8 OF 27 INSPEC (C) 2005 IEE on STN
1.6
            13011
     2000:6475744 INSPEC
                              DN B2000-02-2570D-057
AN
     Submicron silicon carbide CMOS for smartpower applications.
ΤI
ΑU
     Kornegay, K.T. (Sch. of Electr. Eng., Cornell Univ., Ithaca, NY, USA)
     11th International Symposium on Power Semiconductor Devices and ICs.
SO
     ISPSD'99 Proceedings (Cat. No.99CH36312)
     Piscataway, NJ, USA: IEEE, 1999. p.297-300 of xxiii+359 pp. 6 refs.
     Conference: Toronto, Ont., Canada, 26-28 May 1999
     Sponsor(s): IEEE Electron Devices Soc.; Inst. Elec. Eng. of Japan
     Price: CCCC 0 7803 5290 4/99/$10.00
     ISBN: 0-7803-5290-4
DT
     Conference Article
     Application; Practical; Experimental
TC
CY
     United States
LA
     English
L6
     ANSWER 9 OF 27
                     INSPEC (C) 2005 IEE on STN
   TEXT
     1999:6198509 INSPEC
                              DN B1999-05-2570D-001
ΑN
ΤI
     Recent progress of submicron CMOS using 6H-SiC for smart power
     applications.
ΑU
     Man Pio Lam (Motorola Inc., Tempe, AZ, USA); Kornegay, K.T.
SO
     IEEE Transactions on Electron Devices (March 1999) vol.46, no.3, p.546-54.
     16 refs.
     Doc. No.: S0018-9383(99)01683-4
     Published by: IEEE
     Price: CCCC 0018-9383/99/$10.00
     CODEN: IETDAI ISSN: 0018-9383
     SICI: 0018-9383(199903)46:3L.546:RPSC;1-I
     Journal
\mathsf{DT}
     Application; Experimental
TC
CY
     United States
LΑ
     English
     ANSWER 10 OF 27 INSPEC
                             (C) 2005 IEE on STN
1.6
          1999:6164781 INSPEC
                              DN B1999-03-2570P-008
AN
TI
     A silicon carbide CMOS intelligent gate driver circuit with stable
     operation over a wide temperature range.
     Jian-Song Chen (Sch. of Electr. & Comput. Eng., Purdue Univ., West
ΑU
     Lafayette, IN, USA); Kornegay, K.T.; Sei-Hyung Ryu
     IEEE Journal of Solid-State Circuits (Feb. 1999) vol.34, no.2, p.192-204.
SO
     14 refs.
     Doc. No.: S0018-9200(99)00987-7
     Published by: IEEE
     Price: CCCC 0018-9200/99/$10.00
     CODEN: IJSCBC ISSN: 0018-9200
     SICI: 0018-9200(199902)34:2L.192:SCCI;1-F
DT
     Journal
TC
     Application; Practical; Theoretical; Experimental
CY
     United States
LA
     English
     ANSWER 11 OF 27 INSPEC (C) 2005 IEE on STN
1.6
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(FO)
TEXE
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AN 1999:6161866 INSPEC DN B1999-03-1210-012

TI A silicon carbide CMOS intelligent gate driver circuit.

AU Jian-Song Chen; Sei-Hyung Ryu; Kornegay, K.T. (Sch. of Electr. & Comput. Eng., Purdue Univ., West Lafayette, IN, USA)

SO Conference Record of 1998 IEEE Industry Applications Conference.

Thirty-Third IAS Annual Meeting (Cat. No.98CH36242)

New York, NY, USA: IEEE, 1998. p.963-6 vol.2 of 3 vol. xxx+2410 pp. 4 refs.

Conference: St. Louis, MO, USA, 12-15 Oct 1998

Price: CCCC 0 7803 4943 1/98/\$10.00

ISBN: 0-7803-4943-1

DT Conference Article

TC Theoretical; Experimental

CY United States

LA English

L6 ANSWER 12 OF 27 INSPEC (C) 2005 IEE on STN

## FOIL TEXT

AN 1998:6116504 INSPEC DN B9902-1220-006

TI Design of a process variation tolerant **CMOS** opamp in 6H-SiC technology for high-temperature operation.

AU Jian-Song Chen (Texas Instrum. Inc., Dallas, TX, USA); Kornegay, K.T.

SO IEEE Transactions on Circuits and Systems I: Fundamental Theory and Applications (Nov. 1998) vol.45, no.11, p.1159-71. 17 refs.

Doc. No.: S1057-7122(98)07720-4

Published by: IEEE

Price: CCCC 1057-7122/98/\$10.00 CODEN: ITCAEX ISSN: 1057-7122

SICI: 1057-7122(199811)45:11L.1159:DPVT;1-1

DT Journal

TC Application; Practical; Experimental

CY United States

LA English

L6 ANSWER 13 OF 27 INSPEC (C) 2005 IEE on STN



AN 1998:6111440 INSPEC DN B9901-1280-007

TI High-temperature mixed-signal ICs using silicon carbide CMOS technology.

AU Jian-Song Chen; Sei-Hung Ryu (Sch. of Electr. & Comput. Eng., Purdue Univ., West Lafayette, IN, USA); Kornegay, K.T.

SO 1998 Fourth International High Temperature Electronics Conference. HITEC (Cat. No.98EX145)

New York, NY, USA: IEEE, 1998. p.292-5 of vii+332 pp. 4 refs.

Conference: Albuquerque, NM, USA, 14-18 June 1998

Sponsor(s): Air Force Res. Lab.; Sandia Nat. Lab.; Team Speciality

Products; Cree Res.; Honeywell Solid State Electron. Center; AlliedSignal; Northrop Grumman Corp.; Electron. Devices Soc.; Components Packaging &

Manuf. Technol. Soc

Price: CCCC 0 7803 4540 1/98/\$10.00

ISBN: 0-7803-4540-1

DT Conference Article

TC Experimental

CY United States

LA English

L6 ANSWER 14 OF 27 INSPEC (C) 2005 IEE on STN

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janj
Teste
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AN 1998:6045429 INSPEC DN B9811-2575-031

TI PECVD silicon carbide as a chemically resistant material for micromachined transducers.

AU Flannery, A.F.; Mourlas, N.J.; Storment, C.W. (Stanford Univ., CA, USA); Tsai, S.; Tan, S.H.; Heck, J.; Monk, D.; Kim, T.; Gogoi, B.; Kovacs, G.T.A.

SO Sensors and Actuators A (Physical) (1 Oct. 1998) vol.A70, no.1-2, p.48-55. 12 refs.

Doc. No.: S0924-4247(98)00111-3

Published by: Elsevier

Price: CCCC 0924-4247/98/\$19.00 CODEN: SAAPEB ISSN: 0924-4247

SICI: 0924-4247(19981001)A70:1/2L.48:PSCC;1-1

Conference: 9th International Solid State Sensors and Actuators Conference

(Transducers '97). Chicago, IL, USA, 16-19 June 1997

Sponsor(s): IEEE Electron Devices Soc

DT Conference Article; Journal

TC Experimental

CY Switzerland

LA English

L6 ANSWER 15 OF 27 INSPEC (C) 2005 IEE on STN



AN 1998:5992549 INSPEC DN B9809-1220-012

TI A constant input transconductance and rail-to-rail input/output swing SiC CMOS op amp.

AU Jian-Song Chen; Kornegay, K.T. (Sch. of Electr. & Comput. Eng., Purdue Univ., West Lafayette, IN, USA)

SO ISCAS '98. Proceedings of the 1998 IEEE International Symposium on Circuits and Systems (Cat. No.98CH36187)

New York, NY, USA: IEEE, 1998. p.241-4 vol.1 of 6 vol.

(xlv+603+489+674+615+557+656) pp. 6 refs. Conference: Monterey, CA, USA, 31 May-3 June 1998

Price: CCCC 0 7803 4455 3/98/\$10.00

ISBN: 0-7803-4455-3

DT Conference Article

TC New Development; Practical; Theoretical

CY United States

LA English

L6 ANSWER 16 OF 27 INSPEC (C) 2005 IEE on STN



AN 1998:5900992 INSPEC DN B9806-1280-005

TI Design of a silicon carbide smart power switch with stable operation over a wide temperature range.

AU Jian-Song Chen; Kornegay, K.T. (Sch. of Electr. & Comput. Eng., Purdue Univ., West Lafayette, IN, USA)

Proceedings of Midwest Symposium on Circuits and Systems Dedicated to the Memory of Professor Mac Van Valkenburg (Cat. No.97CH36010) Editor(s): Soderstrand, M.A.; Michael, S.

New York, NY, USA: IEEE, 1998. p.123-6 vol.1 of 2 vol. lii+1480 pp. 12 refs.

Conference: Sacramento, CA, USA, 3-6 Aug 1997

Sponsor(s): Univ. California Davis; IEEE Circuits & Syst. Soc

Price: CCCC 0 7803 3694 1/97/\$10.00

ISBN: 0-7803-3694-1

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DT
      Conference Article
      Application; Practical
 TC
      United States
 CY
      English
 LA
 L6
      ANSWER 17 OF 27 INSPEC
                              (C) 2005 IEE on STN
    FOI
      1998:5878529
                   INSPEC
                               DN B9805-7230G-026
 AN
      An uncooled IR imager with 5 mK NEDT.
 ΤI
 ΑU
      Amantea, R.; Knoedler, C.M.; Pantuso, F.P.; Patel, V.K.; Sauer, D.J.;
      Tower, J.R.
      Proceedings of the SPIE - The International Society for Optical
 SO
      Engineering (1997) vol.3061, p.210-22. 3 refs.
      Published by: SPIE-Int. Soc. Opt. Eng
      Price: CCCC 0277-786X/97/$10.00
      CODEN: PSISDG ISSN: 0277-786X
      SICI: 0277-786X(1997)3061L.210:UIWN;1-X
      Conference: Infrared Technology and Applications XXIII. Orlando, FL, USA,
      20-25 April 1997
      Sponsor(s): SPIE
· DT
      Conference Article; Journal
 TC
      Practical; Experimental
 CY
      United States
 LA
      English
 L6
      ANSWER 18 OF 27 INSPEC
                               (C) 2005 IEE on STN
    AN
      1997:5751673
                   INSPEC
                               DN B9712-2575-059
 TI
      PECVD silicon carbide for micromachined transducers.
      Flannery, A.F.; Mourlas, N.J.; Storment, C.W. (Stanford Univ., CA, USA);
 ΑU
      Tsai, S.; Tan, S.H.; Kovacs, G.T.A.
 SO
      Tranducers 97. 1997 International Conference on Solid-State Sensors and
      Actuators. Digest of Technical Papers (Cat. No.97TH8267)
      New York, NY, USA: IEEE, 1997. p.217-20 vol.1 of 2 vol. 1525 pp. 8 refs.
      Conference: Chicago, IL, USA, 16-19 June 1997
      Sponsor(s): IEEE Electron Devices Soc
      Price: CCCC 0 7803 3829 4/97/$10.00
      ISBN: 0-7803-3829-4
 DT
      Conference Article
 TC
      Application; Experimental
 CY
      United States
      English
 LA
 L6
      ANSWER 19 OF 27 INSPEC
                              (C) 2005 FIZ KARLSRUHE on STN
             1997:5750761 INSPEC
                               DN B9712-2570F-007
 ΑN
 ΤI
      Silicon carbide MOSFET integrated circuit technology.
 ΑU
      Brown, D.M.; Downey, E.; Ghezzo, M.; Kretchmer, J.; Krishnamurthy, V.;
      Hennessy, W.; Michon, G. (Gen. Electr. Corp. Res! & Dev. Center,
      Schenectady, NY, USA)
 SO
      Physica Status Solidi A (16 July 1997) vol.162, no.1, p.459-79. 51 refs.
      Published by: Akademie Verlag
      Price: CCCC 0031-8965/97/$10.00+0.25
      CODEN: PSSABA ISSN: 0031-8965
      SICI: 0031-8965(19970716)162:1L.459:SCMI;1-0
 DT
      Journal
      General Review; Practical
 TC
```

- CY Germany, Federal Republic of LA English ANSWER 20 OF 27 INSPEC (C) 2005 IEE on STN 1.6 1997:5730807 INSPEC DN B9712-1265-001 AN ΤI 6H-SiC CMOS digital ICs operating on a 5 V power supply. AU Ryu, S.; Kornegay, K.T.; Cooper, J.A., Jr.; Melloch, M.R. (Sch. of Electr. & Comput. Eng., Purdue Univ., West Lafayette, IN, USA) SO 1997 55th Annual Device Research Conference Digest (Cat. No.97TH8279) New York, NY, USA: IEEE, 1997. p.38-9 of 175 pp. 3 refs. Conference: Fort Collins, CO, USA, 23-25 June 1997 Sponsor(s): IEEE Electron Devices Soc ISBN: 0-7803-3911-8 DTConference Article TC Practical; Experimental CY United States LA English L6 ANSWER 21 OF 27 INSPEC (C) 2005 IEE on STN 30111 INSPEC AN1997:5716833 ΤI elevated temperatures. ΑU Univ., West Lafayette, IN, USA)

  - DN B9711-1220-015
- Design of a silicon carbide CMOS power OPAMP for stable operation at
- Jian-Song Chen; Kornegay, K.T. (Sch. of Electr. & Comput. Eng., Purdue
- Proceedings of 1997 IEEE International Symposium on Circuits and Systems. Circuits and Systems in the Information Age. ISCAS '97 (Cat. No.97CH35987) New York, NY, USA: IEEE, 1997. p.157-60 vol.1 of 4 vol. lxvi+2832 pp. 12 refs.

Conference: Hong Kong, 9-12 June 1997 Price: CCCC 0 7803 3583 X/97/\$10.00

ISBN: 0-7803-3583-X

DTConference Article

TC Theoretical

United States CY

LA English

1.6 ANSWER 22 OF 27 INSPEC (C) 2005 IEE on STN



- AN 1997:5703878 INSPEC DN B9711-2560R-014
- ŤΙ Silicon carbide for power devices.
- Palmour, J.W.; Singh, R.; Glass, R.C.; Kordina, O.; Carter, C.H., Jr. ΑU (Cree Res. Inc., Durham, NC, USA)
- SO ISPSD '97. 1997 IEEE International Symposium on Power Semiconductor Devices and ICs (Cat. No.97CH36086)

New York, NY, USA: IEEE, 1997. p.25-32 of 375 pp. 31 refs.

Conference: Weimar, Germany, 26-29 May 1997

Sponsor(s): VDE; IEEE Electron Devices Soc.; IEE Japan; EUREL

Price: CCCC 0 7803 3993 2/97/\$10.00

ISBN: 0-7803-3993-2

- DTConference Article
- TC Application; General Review; Practical
- CY United States
- LA English
- L6 ANSWER 23 OF 27 INSPEC (C) 2005 IEE on STN

```
DN B9706-1220-014
     1997:5573501 INSPEC
     Class-AB SiC CMOS power opamp with stable voltage gain over wide
TI
     temperature range.
     Chen, J.-S.; Kornegay, K.T. (Sch. of Electr. & Comput. Eng., Purdue Univ.,
ΑU
    West Lafayette, IN, USA)
     IEE Proceedings-Circuits, Devices and Systems (Feb. 1997) vol.144, no.1,
SO
     p.22-8. 13 refs.
     Published by: IEE
     Price: CCCC 1350-2409/97/$10.00
     CODEN: ICDSE7 ISSN: 1350-2409
     SICI: 1350-2409(199702)144:1L.22:CCPO;1-F
DT
     Journal
    Application; Practical; Theoretical; Experimental
TC
CY
     United Kingdom
LA
     English
     ANSWER 24 OF 27 INSPEC
                             (C) 2005 IEE on STN
L6
     1996:5267064 INSPEC
                              DN B9606-2560J-043
AN
     Feasibility of 4.5 kV and 10 kV silicon carbide IGBTs.
ΤI
     Bakowski, M.; Gustafsson, U.; Ramberg, L.P. (Ind. Microelectron. Center,
AU
     Kista, Sweden)
     ESSDERC '94. Proceedings of the 24th European Solid State Device Research
SO
     Editor(s): Hill, C.; Ashburn, P.
     Gif sur Yvette, France: Editions Frontieres, 1994. p.761-4 of xxxiii+854
     pp. 5 refs.
     Conference: Edinburgh, UK, 11-15 Sept 1994
     Sponsor(s): IEEE
     ISBN: 2-86332-157-9
     Conference Article
DT
TC
     Practical; Experimental
     France
CY
     English
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     ANSWER 25 OF 27 INSPEC (C) 2005 IEE on STN
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